# NSN 5961-01-227-1942

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# Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

0.450 inches

**Overall Width:** 

1.050 inches

# Mounting Facility Quantity:

2

#### Internal Configuration:

Field effect

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

#### **Mounting Method:**

## Unthreaded hole

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

500.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source

## **Current Rating Per Characteristic:**

250.00 microamperes zero-gate-voltage drain current

### Power Rating Per Characteristic:

125.0 watts total device dissipation

#### Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

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